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High Performance Schottky Rectifier, 1.0 A



SMB (DO-214AA)

PRIMARY CHARACTERISTICS			
I _{F(AV)}	1.0 A		
V _R	15 V		
V _F at I _F	0.21 V		
I _{RM}	35 mA at 100 °C		
T _J max.	125 °C		
E _{AS}	1.0 mJ		
Package	SMB (DO-214AA)		
Circuit configuration	Single		

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- 125 °C T_J operation (V_R < 5 V)
- Optimized for OR-ing applications
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-10BQ015HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	А		
V _{RRM}		15	V		
I _{FSM}	t _p = 5 μs sine	140	А		
V _F	1.0 A _{pk} , T _J = 125 °C	0.21	V		
TJ	Range	-55 to +125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ015HM3	UNITS	
Maximum DC reverse voltage	V _R	15	N/	
Maximum working peak reverse voltage	V _{RWM}	25	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _L = 134 °C, rectangular waveform		1.0	А
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	140	
non-repetitive surge current I _{FSM} See fig. 7	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	40	A	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1.0	А

Revision: 29-Jul-2021

Document Number: 95722

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.33	V
		2 A		0.39	
		1 A	- T _J = 125 °C	0.21	
		2 A		0.29	
Maximum reverse leakage current See fig. 2	I _{RM}	T _J = 25 °C	V _R = Rated V _R	0.5	mA
		T _J = 100 °C		35	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		-	V
Forward slope resistance	r _t			-	mΩ
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		390	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	U
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°0.444
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.10	g
			0.003	oz.
Marking device		Case style SMB (DO-214AA)	1(C

Notes

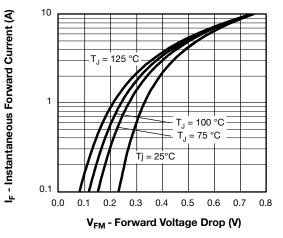
(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

(2) Mounted 1" square PCB

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Fig. 1 - Maximum Forward Voltage Drop Characteristics

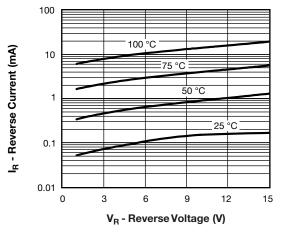


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

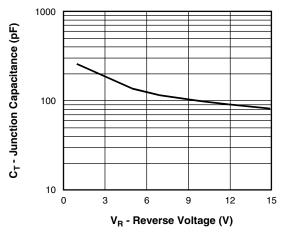


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

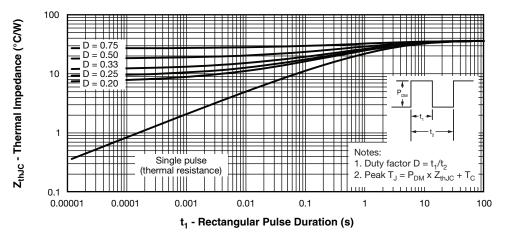


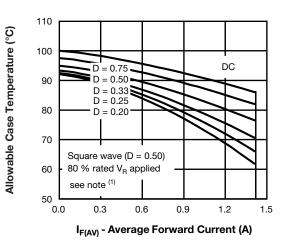
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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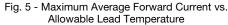


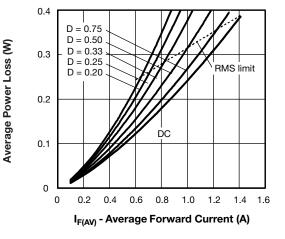
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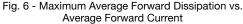


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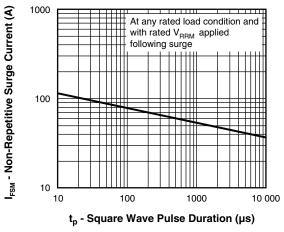


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = 80 \ \% \mbox{ rated } \mbox{V}_{R} \end{array}$

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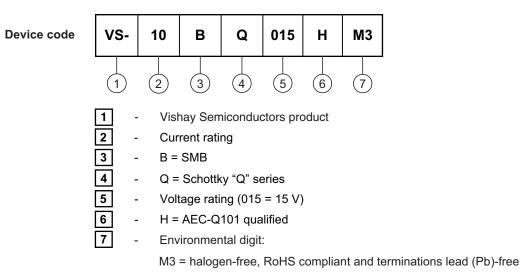
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ORDERING INFORMATION TABLE

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 ORDERING INFORMATION (Example)

 PREFERRED P/N
 PREFERRED PACKAGE CODE
 MINIMUM ORDER QUANTITY
 PACKAGING DESCRIPTION

 VS-10BQ015HM3/5BT
 5BT
 3200
 13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95401	
Part marking information	www.vishay.com/doc?95403	
Packaging information	www.vishay.com/doc?95404	
SPICE model	www.vishay.com/doc?95666	

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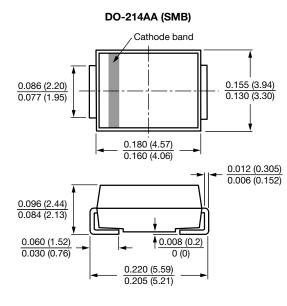


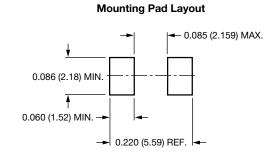
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)









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